



ECH8503

Bipolar Transistor -50V, -5A, Low $V_{CE(sat)}$ PNP Dual ECH8

ON Semiconductor®

<http://onsemi.com>

Features

- Composite type, facilitating high-density mounting
- Mounting height 0.9mm
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

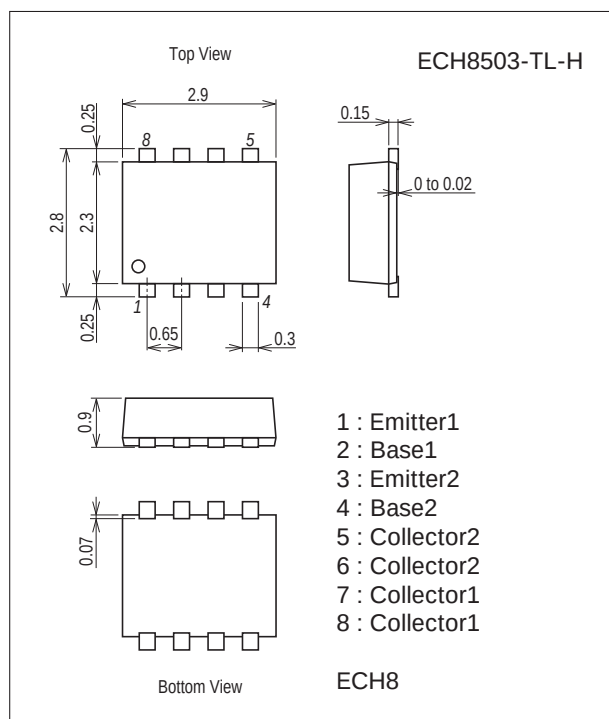
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		-50	V
Collector-to-Emitter Voltage	V_{CEO}		-50	V
Emitter-to-Base Voltage	V_{EBO}		-6	V
Collector Current	I_C		-5	A
Collector Current (Pulse)	I_{CP}		-10	A
Base Current	I_B		-1	A
Collector Dissipation	P_C	When mounted on ceramic substrate (900mm ² ×0.8mm) 1unit	1.3	W
Total Dissipation	P_T	When mounted on ceramic substrate (900mm ² ×0.8mm)	1.6	W
Junction Temperature	T_j		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

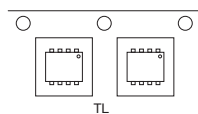
7011A-008



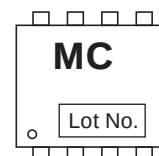
Product & Package Information

- Package : ECH8
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

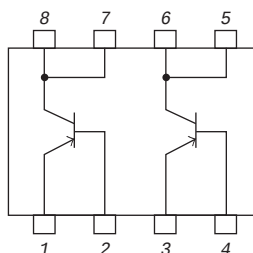
Taping Type : TL



Marking



Electrical Connection

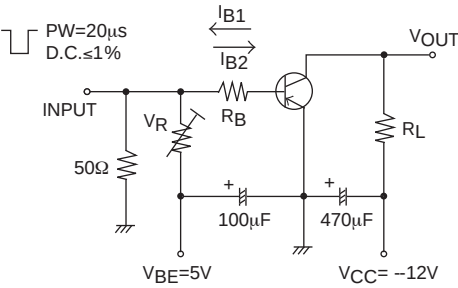


Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	VCB= -50V, IE=0A			-0.1	μA
Emitter Cutoff Current	IEBO	VEB= -4V, IC=0A			-0.1	μA
DC Current Gain	hFE	VCE= -2V, IC= -500mA	200		560	
Gain-Bandwidth Product	fT	VCE= -10V, IC= -500mA		280		MHz
Output Capacitance	Cob	VCB= -10V, f=1MHz		42		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)1	IC= -1A, IB= -50mA		-60	-100	mV
	VCE(sat)2	IC= -2.5A, IB= -125mA		-110	-190	mV
Base-to-Emitter Saturation Voltage	VBE(sat)	IC= -2.5A, IB= -125mA		-0.9	-1.1	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC= -10μA, IE=0A	-50			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC= -1mA, RBE=∞	-50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE= -10μA, IC=0A	-6			V
Turn-On Time	ton	See specified Test Circuit.		30		ns
Storage Time	tstg			170		ns
Fall Time	tf			17		ns

Note) The specifications shown above are for each individual transistor.

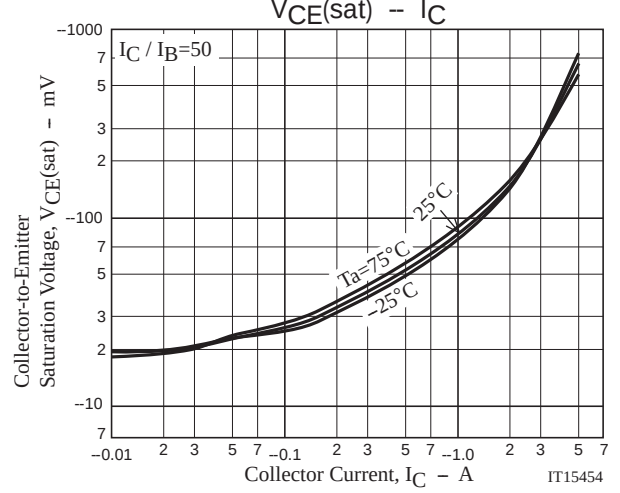
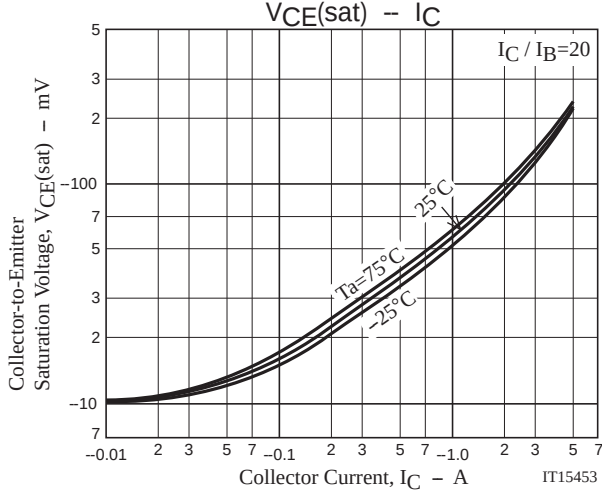
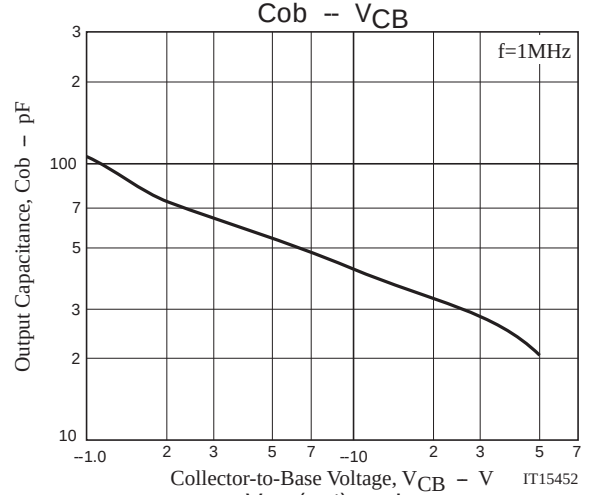
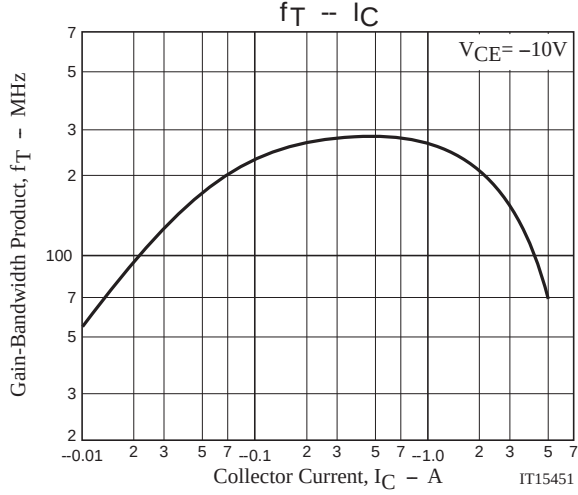
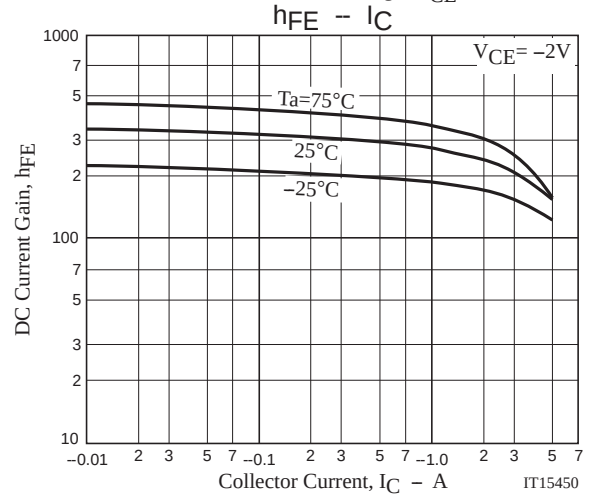
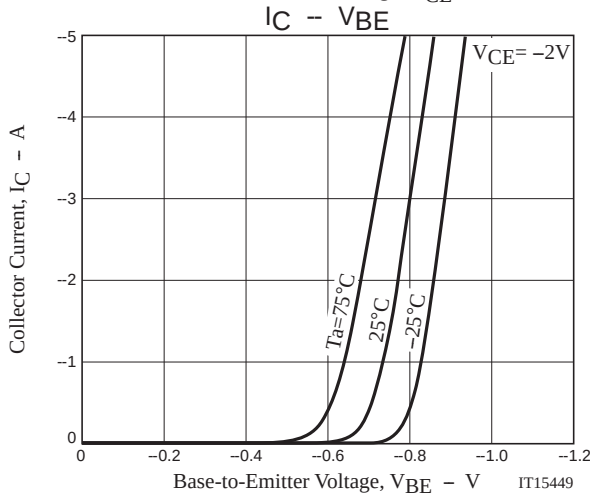
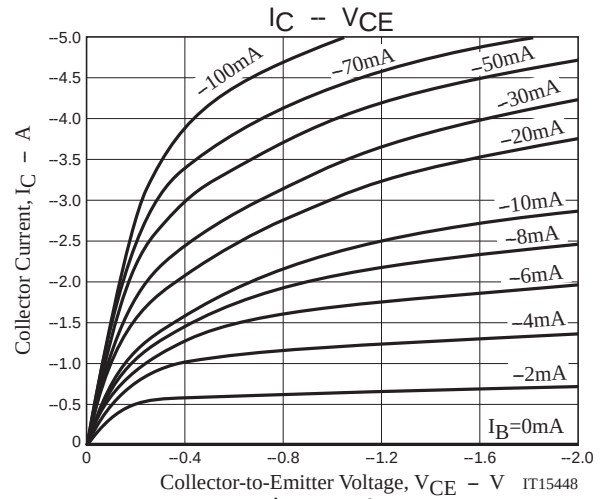
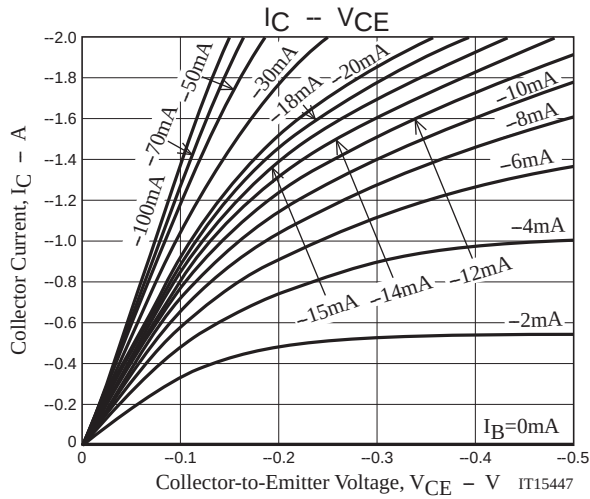
Switching Time Test Circuit

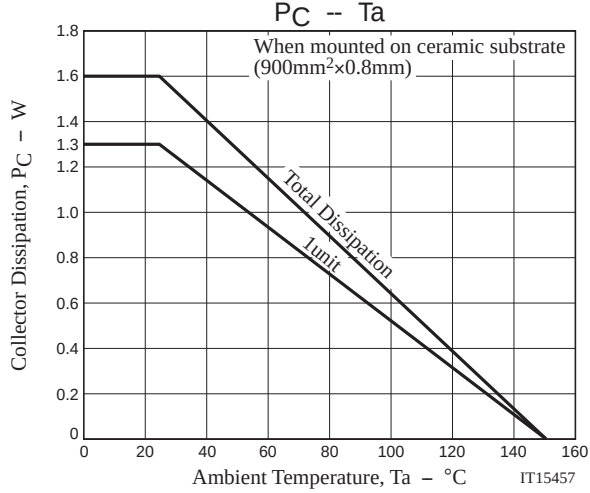
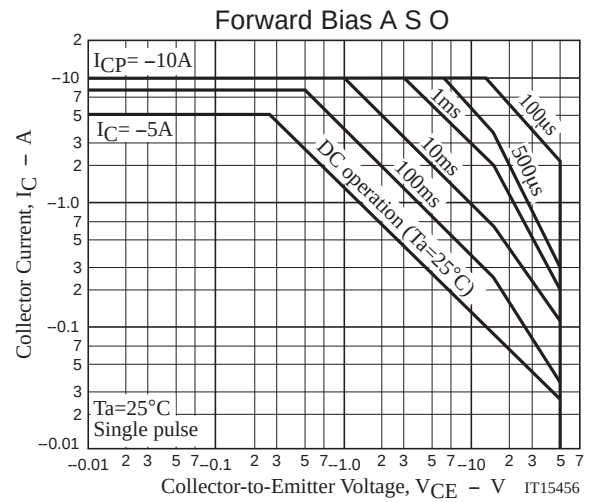
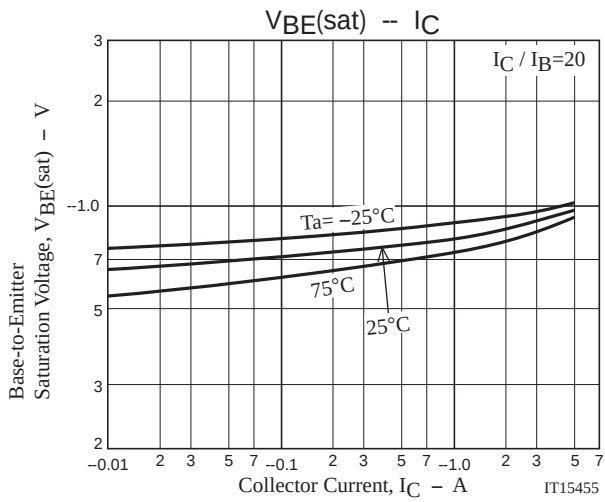


$I_C = -20\text{mA}$
 $I_{B1} = 20\text{mA}$
 $I_{B2} = -2.5\text{mA}$

Ordering Information

Device	Package	Shipping	memo
ECH8503-TL-H	ECH8	3,000pcs./reel	Pb Free and Halogen Free





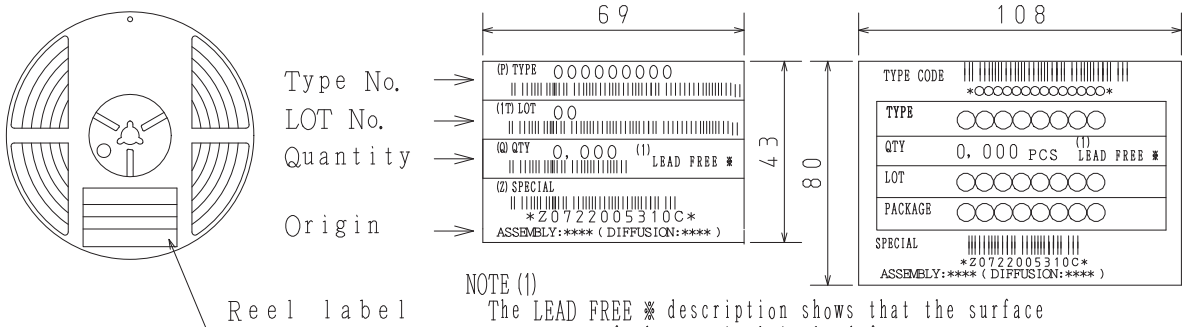
Embossed Taping Specification

ECH8503-TL-H

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
ECH8	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

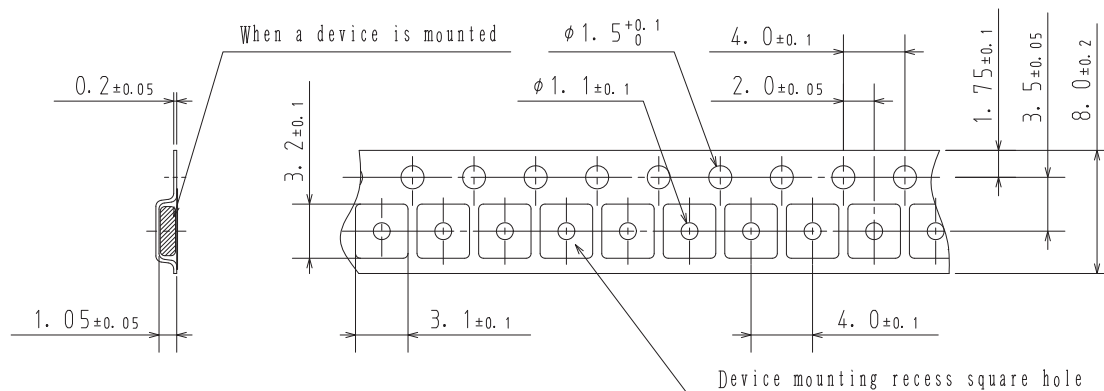
Packing method



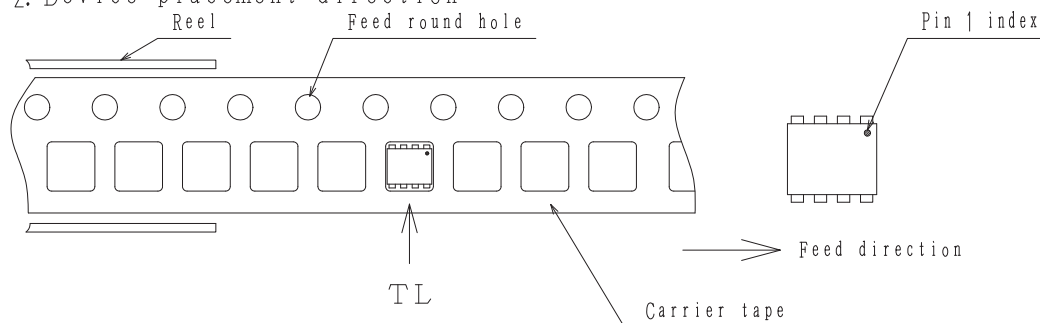
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)

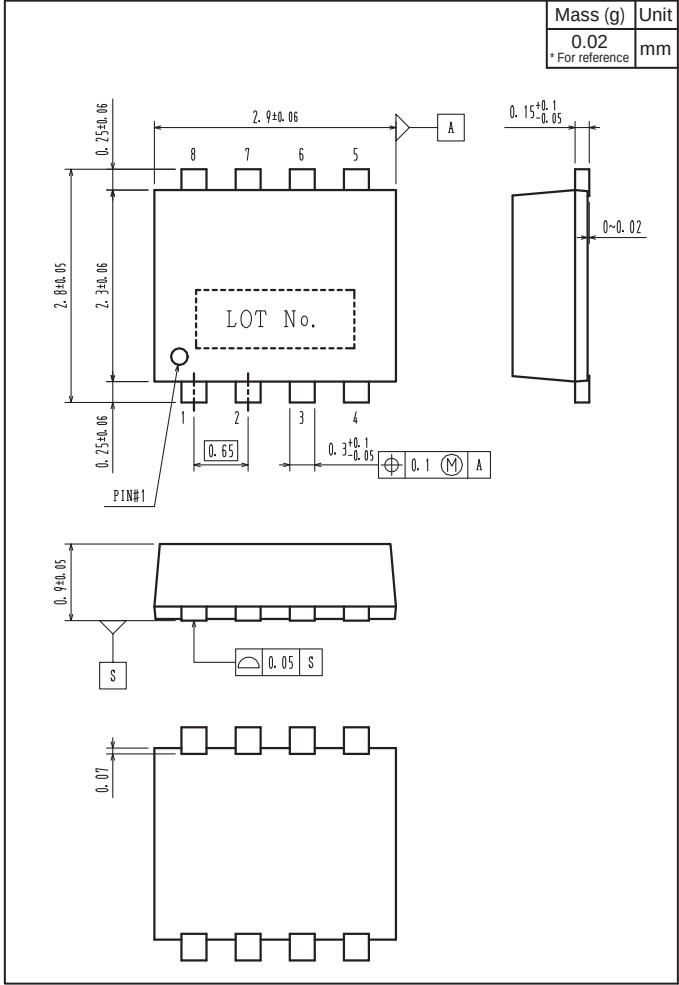


2-2. Device placement direction

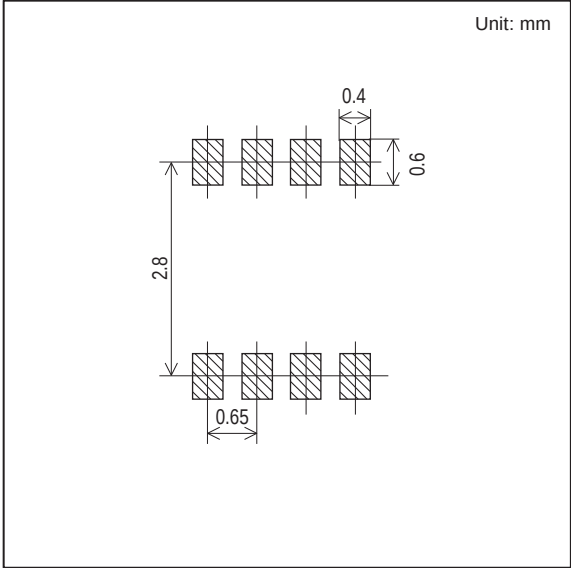


Those with pin 1 index on the feed hole side.....TL

Outline Drawing
ECH8503-TL-H



Land Pattern Example



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